Metal complexes of selenophosphinates from reactions with $(R_2PSe)_2Se: [M(R_2PSe_2)_n] (M = Zn^{II}, Cd^{II}, Pb^{II}, In^{III}, Ga^{III}, Cu^{I}, Bi^{III}, Ni^{II}; R = {}^{i}Pr, Ph)$ and $[Mo^V_2O_2Se_2(Se_2P^iPr_2)_2]$

Chinh Q. Nguyen, Adekunle Adeogun, Mohammad Afzaal, Mohammad A. Malik and Paul O'Brien*

Received (in Cambridge UK) 3rd March 2006, Accepted 31st March 2006 First published as an Advance Article on the web 21st April 2006 DOI: 10.1039/b603198f

The reactions of bis(dialkylselenophosphinyl)selenide with a series of metals have been investigated: synthesis of several metal selenophosphinate complexes and their structures are reported.

The coordination chemistry of dithiophosphinate complexes has been well explored and the complexes' potential as single-source precursors (SSPs) for metal sulfide thin films has been shown.¹ There are no reports in the literature for a structurally characterized isolated selenophosphinate such as $(R_2PSe)_2Se$, and only a few reports on their metal complexes. The methods reported in the literature for the preparation of selenophosphates or selenophosphinates are not always reproducible.²

In this paper, we report the reactions of bis(dialkylselenophosphinyl)selenide $(R_2PSe)_2Se$ with a range of metals resulting in novel and facile syntheses of metal dialkyldiselenophosphinato complexes, and the complexes' characterization in solution and solid state.

The compound $(R_2PSe)_2Se$ $(R = {}^iPr, Ph)$ was prepared by the reaction of NEt₃ with iPr_2PCl , HSiCl₃ and Se in toluene (see accompanying communication).³ The reaction of this compound with different metal salts was then carried out in methanolic solutions to give the metal complexes as precipitates which were subsequently recrystallized from dichloromethane or toluene before further analyses. The complexes are soluble in chloroform, toluene or dichloromethane. All are stable at room temperature under open atmosphere for months which makes them potentially useful as SSPs for the deposition of metal selenide thin films or nanoparticles.

The copper complex **1** is based on the tetramer $[Cu_4(^iPr_2PSe_2)_4]$ (Fig. 1). None of the ligands are chelating, all four ligands are bridging. One of the seleniums is bound to phosphorus and copper only whilst the other selenium is bonded to two copper atoms and one phosphorus atom in each ligand. Each Cu is bonded to three Se atoms, giving overall a cubane structure. The Se–Cu–Se bond angles range from 128.733(2) to 101.419(2)° to give a distorted trigonal planar geometry at each Cu centre. The Cu–Se bond distances range from 2.437(5) to 2.369(5) Å. The dithiocarbamato or dithiophosphinato ligands chelate to the copper centre as expected.^{4,5}

In an analogous reaction, molybdenum complex **2** $[Mo_2O_2Se_2(Se_2P^iPr_2)_2]$ is formed. In a dimeric structure, each ligand chelates to one Mo atom and the two Mo atoms are doubly bridged by two selenium atoms (Fig. 2). The geometry around Mo is distorted square pyramidal. The structure is similar to that of $[Mo_2O_2(\mu-O)(\mu-S)(S_2CNPr_2)_2].^6$





Fig. 1 Thermal ellipsoid plot (50% probability) of the structure of 1. Selected bond distances (Å) and angles (°): Cu(1)–Se(1), 2.401(5); Cu(1)–Se(7), 2.425(5); Cu(1)–Se(4), 2.437(5); Cu(2)–Se(7), 2.369(5); Cu(2)–Se(3), 2.387(5); Cu(2)–Se(6), 2.409(5); Cu(3)–Se(5), 2.388(5); Cu(3)–Se(1), 2.392(5); Cu(3)–Se(8), 2.407(5); Cu(4)–Se(2), 2.398(5); Cu(4)–Se(3), 2.398(5); Cu(4)–Se(5), 2.409(5); Se(1)–Cu(1)–Se(7), 120.29(2); Se(1)–Cu(1)–Se(4), 110.56(2); Se(7)–Cu(2)–Se(3), 124.99(2); Se(7)–Cu(2)–Se(6), 128.73(2); Se(3)–Cu(2)–Se(6), 101.42(2); Se(5)–Cu(3)–Se(8), 121.48(2); Se(1)–Cu(3)–Se(8), 111.91(2); Se(2)–Cu(4)–Se(5), 113.64(2); Se(3)–Cu(4)–Se(5), 120.61(2).

The indium complex **3** shows (Fig. 3) the expected $[In({}^{i}Pr_{2}PSe_{2})_{3}]$ molecule. All three diselenophosphinate ligands are chelating to form three four membered rings (Se–P–Se–In) with In–Se bond distances range from 2.729(6) to 2.768(6) Å. The geometry on indium is trigonally distorted octahedral due to the



Fig. 2 Thermal ellipsoid plot (50% probability) of the structure of **2**. Selected bond distances (Å) and angles (°): Mo(1)-O(1), 1.656(7); Mo(1)-Se(3), 2.434(1); Mo(1)-Se(4), 2.451(2); Mo(1)-Se(2), 2.587(1); Mo(1)-Se(1), 2.606(1); Mo(2)-O(2), 1.663(7); Mo(2)-Se(3), 2.441(1); Mo(2)-Se(4), 2.454(2); Mo(2)-Se(6), 2.595(1); Mo(2)-Se(5), 2.596(1); O(1)-Mo(1)-Se(3), 109.00(2); O(1)-Mo(1)-Se(4), 105.70(2); Se(3)-Mo(1)-Se(4), 105.77(5); O(1)-Mo(1)-Se(2), 107.70(2); Se(3)-Mo(1)-Se(2), 140.93(6); Se(4)-Mo(1)-Se(2), 76.46(5); O(1)-Mo(1)-Se(1), 103.0(3); Se(3)-Mo(1)-Se(1), 78.64(4); Se(4)-Mo(1)-Se(1), 147.43(6); Se(2)-Mo(1)-Se(1), 80.46(4).



Fig. 3 Thermal ellipsoid plot (50% probability) of the structure of 3. Selected bond distances (Å) and angles (°): In(2)–Se(9), 2.729(6), In(2)–Se(8), 2.733(6); In(2)–Se(12), 2.742(6); In(2)–Se(7), 2.752(6); In(2)–Se(10), 2.767(6); In(2)–Se(11), 2.768(6); Se(9)–In(2)–Se(8), 96.34(2); Se(9)–In(2)–Se(12), 164.280(2), Se(8)–In(2)–Se(12), 96.16(2); Se(9)–In(2)–Se(7), 96.87(2); Se(8)–In(2)–Se(7), 80.31(2); Se(12)–In(2)–Se(7), 94.60(2); Se(9)–In(2)–Se(10), 80.84(2); Se(8)–In(2)–Se(10), 88.88(2); Se(12)–In(2)–Se(10), 89.91(2); Se(7)–In(2)–Se(10), 168.67(2); Se(9)–In(2)–Se(11), 89.42(2); Se(8)–In(2)–Se(11), 169.47(2); Se(12)–In(2)–Se(11), 79.79(2); Se(7)–In(2)–Se(11), 90.27(2); Se(10)–In(2)–Se(11), 100.77(2).

restricted bite angle of the chelating diselenophosphinate ligand. The structure is similar to those reported for $[In(Ph_2PSe_2)_3]^7$ or the sulfur analogue $[In(Ph_2PS_2)_3]^8$

The structure of $[Ga({}^{i}Pr_2PSe_2)_3](4)$ (Fig. 4) has a four coordinate gallium centre in contrast to the six coordinate indium. Until recently⁹ all of the reports on structurally characterized pairs of analogues In/Ga tris(chelates) with (O, O') or (S, S') ligands have been shown to be isostructural.^{10,11} The first such structure of a gallium complex was reported by us for tris(di-isobutyldithiophosphinato) gallium(III) [Ga(Ph₂PS₂)₃].⁹ The structure consists of one chelating and two pendant di-isopropyldiselenophosphinate ligands in a distorted tetragonal geometry. The bite angle of the chelating ligand (90.42(15)°) is considerably larger than that of the indium complex (80.84(19), 80.31(16), 79.79(16)°) and the tetrahedral angle between the sulfur atoms of the two pendant ligands is 115.97(16)°. The bond distances between Se–Ga in chelating ligand (2.446(4) Å and 2.451(4) Å) are larger than those of the



Fig. 4 Thermal ellipsoid plot (50% probability) of the structure of 4. Selected bond distances (Å) and angles (°): Ga(1)–Se(5), 2.385(4); Ga(1)–Se(3), 2.396(5); Ga(1)–Se(2), 2.446(4); Ga(1)–Se(1), 2.451(4); Se(5)–Ga(1)–Se(3), 115.97(2); Se(5)–Ga(1)–Se(2), 115.89(2); Se(3)–Ga(1)–Se(2), 110.75(1); Se(5)–Ga(1)–Se(1), 112.49(2); Se(3)–Ga(1)–Se(1), 108.32(1); Se(2)–Ga(1)–Se(1), 90.42 (2).

pendant ligands (2.396(5), 2.385 (4) Å) which shows that the negative charge is localized on a single donor atom in pendant ligands. We have also analysed the X-ray structure of $[Ga(Ph_2PSe_2)_3]$ which showed similar coordination and will be reported later.

The compounds **5–18** were prepared in a similar way.† It is worth noting that $(R_2PSe)_2Se$ ($R = {}^iPr$, Ph) breaks its phosphorus selenium bond in each case and acts as a source of dialkylselenophosphinate anion $[R_2PSe_2]^-$. In the copper complex the ligand is bridging, in the molybdenum complex chelating and bridging, in the indium complex chelating only and in the gallium complex only one is chelating whilst the other two are pendant.

All these complexes are potentially useful single source precursors. Preliminary chemical vapour deposition experiments of Cu, Mo, Cd and Zn complexes produce high quality thin films and nanoparticles. Detailed deposition studies on these complexes are under way and will be reported else where.

The authors thank RCUK and the EPSRC for funding a Basic technology project. CQN would like to acknowledge the Government of Vietnam for funding.

Notes and references

† All the reactions were performed under a nitrogen atmosphere by using standard Schlenk techniques. All chemicals were bought from Aldrich Chemical Company Limited and used as received. Solvents were distilled prior to use. NMR spectra were obtained with chloroform-D6 solution using a Bruker AC300 FTNMR instrument. Elemental analysis was performed by the University of Manchester micro-analytical laboratory. Single crystal X-ray crystallography measurements were made using graphite monochromated Mo Kα radiation on a Bruker APEX diffractometer. The structures were solved by direct methods and refined by full-matrix least-squares on $F^{2.12}$ All calculations were carried out using the SHELXTL package.¹³ All non-hydrogen atoms were placed in calculated positions, assigned isotropic atoms. CCDC numbers, 282910 (1), 282909 (2), 291036 (3), 291037 (4). For crystallographic data in CIF or other electronic format see DOI: 10.1039/b603198f

 $({}^{i}Pr_{2}PSe)_{2}Se$ (A) and $(Ph_{2}PSe)_{2}Se$ (B) were prepared as discussed in the preceding paper.^{3}

[Cu₄(Pr_2PSe_2)_4] (1). In a typical experiment the solution of CuCl₂ (1.0 g, 7.5 mmol) in 20 ml MeOH was added dropwise to a solution of (Pr_2PSe_2Se (A) (7 g, 15 mmol) in 100 ml of MeOH. The mixture was stirred for 1 h at room temperature under atmospheric pressure, forming a light yellow precipitate, which was filtered, washed with MeOH and recrystallized in dichloromethane to obtain light yellow crystals of 1 (6.6 g, yield 65%). Mp 230–235 °C. Elemental analysis (found: C, 21.94; H, 4.30; P, 9.01; calc. for C₂₄H₅₆P₄Se₈Cu₄: C, 21.28; H, 4.17; P, 9.15%;) ¹H NMR $\delta = 1.35$ ppm (ddd, 12H, J = 7.0 Hz, J = 19.2 Hz, J = 26.1 Hz, $2 \times CH(CH_{3})_2$), 2.44 ppm (dq, 2H, J = 5.5 Hz, J = 14.1 Hz, $2 \times CH(CH_{3})_2$).

[Mo₂O₂Se₂(¹Pr₂PSe₂)₂] (2). We followed the process of making 1 but used MoCl₅ (2.05 g, 7.5 mmol), and obtained brown crystals of 2 (4.2 g, yield 37%). Mp 295–300 °C. Elemental analysis (found: C, 16.00; H, 2.88; Mo, 20.92%; calc. for $C_{12}H_{28}O_2P_2Se_6Mo_2$: C,15.47; H, 3.03; Mo, 20.59%)

[In(ⁱPr₂PSe₂)₃] (3). We followed the process of making 1 but used InCl₃ (1.1 g, 5 mmol), to obtain light yellow crystals of 3 (2.5 g, yield 53.1%). Mp 183 °C. Elemental analysis (found: C, 23.09; H, 4.37; P, 10.22; In, 12.02%; calc. for C₁₈H₄₂P₃Se₆In: C, 23; H, 4.5; P, 9.88; In 12.21%; ¹H NMR δ = 1.37 ppm (dd, 36H, *J* = 6.8 Hz, *J* = 20.4 Hz, 6 × CH(CH₃)₂), 2.24 ppm (dq, 6H, *J* = 2.7 Hz, *J* = 6.9 Hz, 6 × CH(CH₃)₂).

[Ga(¹Pr₂PSe₂)₃] (4). We followed the process of making 1 but used GaCl₃ (0.88 g, 5 mmol), and obtained light yellow crystals of 4 (2.8 g, yield 62.6%). Mp 180 °C. Elemental analysis (found: C, 24.19; H, 4.71; P, 9.99; Ga, 7.58%; calc. for C₁₈H₄₂P₃Se₆Ga: C, 24.16; H, 4.73; P, 10.38; Ga 7.79%; ¹H NMR δ = 1.31 ppm (dd, 36H, *J* = 6.9 Hz, *J* = 20.2 Hz, 6 × CH(CH₃)₂), 2.29 ppm (dq, 6H, *J* = 6.8 Hz, *J* = 11.7 Hz, 6 × CH(CH₃)₂).

 $[Pb(^{\dagger}Pr_2PSe_2)_2]$ (5). We followed the process of making 1 but used Pb(CH₃COO)₂ (2.9 g, 7.5 mmol), and obtained yellow crystals of 5 (3.6 g, yield 63.4%). Mp 140 °C. Elemental analysis (found: C, 19.07; H, 3.58; P, 7.69; Pb, 26.67%; calc. for C₁₂H₂₈P₂Se₄Pb: C, 19.03; H, 3.73; P, 8.18; Pb,

27.36%; ¹H NMR δ = 1.29 ppm (dd, 24H, *J* = 6.8 Hz, *J* = 20.3 Hz, 4 × CH(CH₃)₂), 2.16 ppm (dq, 4H, *J* = 6.8 Hz *J* = 12.1, 4 × CH(CH₃)₂).

 $[Zn(^{1}Pr_{2}PSe_{2})_{2}]$ (6). We followed the process of making 1 but used ZnCl₂ (1.02 g, 7.5 mmol), and obtained colourless crystals of 6 (2.5 g, yield 54.3%). Mp 120 °C. Elemental analysis (found: C, 23.49; H, 4.46; P, 10.29; Zn, 10.48%; calc. for C₁₂H₂₈P₂Se₄Zn: C, 23.42; H, 4.59; P,10.06; Zn, 10.62%; ¹H NMR δ = 1.25 ppm (dd, 24H, J = 6.8 Hz, J = 20.7 Hz, 4 × CH(CH₃)₂), 2.17 ppm (dq, 4H, J = 6.9Hz, J = 11.1Hz, 4 × CH(CH₃)₂).

[Cd(¹Pr₂PSe₂)₂] (7). We followed the process of making 1 but used CdCl₂ (1.37g, 7.5 mmol), and obtained colourless crystals of 7 (3.0 g, yield 60.3%). Mp 200 °C. Elemental analysis (found: C, 22.69; H, 4.32; P, 9.39; Cd, 16.37%; calc. for C₁₂H₂₈P₂Se₄Cd: C, 21.75; H, 4.26; P, 9.35; Cd, 16.97%; ¹H NMR δ = 1.27 ppm (dd, 24H, *J* = 6.8 Hz, *J* = 20.5 Hz, 4 × CH(CH₃)₂), 2.17 ppm (dq, 4H, *J* = 6.8 Hz, *J* = 11.4 Hz, 4 × CH(CH₃)₂).

[Bi(Se₂P'Pr₂)₃] (8). We followed the process of making 1 but used Bi(NO₃)·5H₂0 (2.4 g, 5 mmol), to obtain orange crystals of **8** (3.1 g, yield 61.0%). Mp 172 °C. Elemental analysis (found: C, 20.33; H, 3.94; P, 7.56%; calcd for C₁₈H₄₂P₃Se₆Bi: C, 20.90; H, 4.09; P, 8.98%); ¹H NMR δ = 1.30 ppm (dd, 36H, *J* = 6.8 Hz *J* = 20.5 Hz, 6 × CH(CH₃)₂), 2.23 ppm (dq, 6H, *J* = 6.9 Hz, *J* = 11.5 Hz, 6 × CH(CH₃)₂).

 $[Co(Se_2P^iPr_2)_2]$ (9). We followed the process of making 1 but used CoCl₂·6H₂O (1.77 g, 7.5 mmol), to obtain light green crystals of 9 (2.0 g, yield 66.2%). Mp 275 °C. Elemental analysis (found: C, 24.04; H, 4.72; P, 10.08%; calc. for C₁₂H₂₈P₂Se₄Co: C, 23.67; H, 4.64; P, 10.17%); ¹H NMR $\delta = 1.37$ ppm (dd, 24H, J = 6.8 Hz, J = 20.4 Hz, $4 \times$ CH(CH₃)₂), 2.16 ppm (m, 4H, $4 \times$ CH(CH₃)₂).

 $[Ni(Se_2P^iPr_2)_2]$ (10). We followed the process of making 1 but used Ni(NO₃)₂·6H₂0 (2.18 g, 7.5 mmol), to obtained green crystals of 10 (2.1 g, yield 69.1%). Mp 173–175 °C. Elemental analysis (found: C, 23.88; H, 4.58; P, 9.92%; calc. for C₁₂H₂₈P₂Se₄Ni: C, 23.67; H, 4.64; P, 10.17%); ¹H NMR δ = 1.40 ppm (m, 12H, CH(CH₃)₂), 2.10 ppm (m, 2H, CH(CH₃)₂).

[In(Ph₂PSe₂)₃] (11). The solution of InCl₃ (1.1 g, 5 mmol) in 20 mL MeOH was added dropwise to solution of (Ph₂PSe)₂Se (**B**)(9.1 g, 15 mmol) in 150 ml of MeOH. The mixture was stirred for 1 h at room temperature under atmospheric pressure forming a light yellow precipitate, which was filtered, washed with MeOH and re-crystallized in dichloromethane to obtain yellow crystals of 11 (3.8 g, yield 66.6%). Mp 187 °C. Elemental analysis (found: C, 36.68; H, 2.56; P, 8.21; In, 9.63%; calc. C₃₆H₃₀P₃Se₆In: C, 37.79; H, 2.64; P, 8.12; In 10.04%). ¹H NMR δ = 7.43 ppm (m, 18H, 6 × *p*-Ph and 6 × *m*-Ph), 7.89 ppm (ddd, 12H, *J* = 2.0 Hz, *J* = 7.5 Hz, *J* = 15.4 Hz, 6 × *o*-Ph).

[Pb(Ph₂PSe₂)₂] (12). We followed the process of making 11 but used Pb(CH₃COO)₂·3H₂O (2.9 g, 7.5 mmol), and obtained yellow crystals of 12 (4.5 g, yield 67.2%). Mp 235 °C. Elemental analysis (found: C, 32.48; H, 2.24; P, 6.40; Pb, 22.47%; calc. for C₂₄H₂₀P₂Se₄Pb: C, 32.27; H, 2.26; P, 6.93; Pb, 23.19%); ¹H NMR δ = 7.39 ppm (m, 4H, 4 × *p*-Ph), 5.51 ppm (m, 8H, 4 × *m*-Ph), 7.85 ppm (m, 8H, 4 × *o*-Ph).

 $[Zn(Ph_2PSe_2)_2]$ (13). We followed the process of making 11 but used ZnCl₂ (1.02 g, 7.5 mmol), and obtained light yellow crystals of 13 (3.5 g, yield 62.1%). Mp 302 °C. Elemental analysis (found: C, 38.52; H, 2.59; P, 8.20; Zn, 8.48%; calc. for C₁₂H₂₀P₂Se₄Zn: C, 38.35; H, 2.68; P, 8.24; Zn, 8.70%); ¹H NMR δ = 7.44 ppm (m, 12H, 4 × *p*-Ph and 4 × *m*-Ph), 7.87 ppm (ddd, 8H, *J* = 3.9 Hz, *J* = 7.1 Hz, *J* = 8.9 Hz, 4 × *o*-Ph).

[Cd(Ph₂PSe₂)₂] (14). We followed the process of making 11 but used CdCl₂ (1.37 g, 7.5 mmol), and obtained light yellow crystals of 14 (4.0 g, yield 66.7%). Mp 309 °C. Elemental analysis (found: C, 36.11; H, 2.52; P, 7.48; Cd, 13.93%; calc. for $C_{24}H_{20}P_2Se_4Cd$: C, 36.09; H, 2.52; P, 7.76; Cd, 14.08%); ¹H NMR δ = 7.43 ppm (m, 12H, 4 × *p*-Ph and 4 × *m*-Ph), 7.88 (m, 8H, 4 × *o*-Ph).

[Ga(Ph₂PSe₂)₃] (15). We followed the process of making 11 but used GaCl₃ (0.88 g, 5 mmol), and obtained yellow crystals of 15 (3.6 g, yield 65.5%). Mp 241 °C. Elemental analysis (found: C, 39.56; H, 2.76; P, 8.74; Ga 5.76%; calc. for $C_{36}H_{30}P_3Se_6Ga: C, 39$; H, 2.75; P, 8.45; Ga, 6.34%); ¹H NMR δ = 7.33 ppm (m, 18H, 6 × *p*-Ph and 6 × *m*-Ph), 7.76 ppm (dd, 12H, *J* = 6.9 Hz, *J* = 15.1 Hz, 6 × *o*-Ph).

[Bi(Ph₂PSe₂)₃] (16). We followed the process of making 11 but used Bi(NO₃)₃·6H₂0 (2.4 g, 5 mmol), and obtained orange crystals of 16 (3.9 g, yield 63.5%). Mp 203 °C. Elemental analysis (found: C, 34.67; H, 2.38; P, 7.53%; calc. for C₃₆H₃₀P₃Se₆Bi: C, 34.92; H, 2.44; P, 7.50%). ¹H NMR δ = 7.39 ppm (dd, 6H, *J* = 2.8 Hz, *J* = 7.6 Hz, 6 × *p*-Ph) 7.45 ppm (ddd, 12H, *J* = 3.2 Hz, *J* = 5.9 Hz, *J* = 7.4 Hz, 6 × *m*-Ph), 7.85 ppm (dd, 12H, *J* = 7.0 Hz, *J* = 15.4 Hz, 6 × *o*-Ph).

[Ni(Ph₂PSe₂)₂] (17). We followed the process of making 11 but used Ni(NO₃)₂·6H₂0 (2.18 g, 7.5 mmol), and obtained green crystals of 17 (3.3 g,

yield 60%). Mp 220 °C. Elemental analysis (found: C, 38.67; H, 2.77; P, 8.29%; calc. for $C_{24}H_{20}P_2Se_4Ni:$ C, 38.70; H, 2.71; P, 8.32%).

 $[Co(Ph_2PSe_2)_2]$ (18). We followed the process of making 11 but used CoCl₂·6H₂0 (1.77 g, 7.5 mmol), and obtained green crystals of 18 (3.0 g, yield 57%). Mp 302 °C. Elemental analysis (found: C, 39.14; H, 2.98; P, 8.03%; calc. for C₂₄H₂₀P₂Se₄Co: C, 38.69; H, 2.71; P, 8.31%).

Crystal data for 1: $C_{24}H_{56}Cu_4P_4Se_8$, $M_r = 1354.41$, monoclinic, space group P2(1)/n, a = 12.9380(16) Å, b = 17.527(2) Å, c = 18.617(2) Å, $\alpha = 90$, $\beta = 91.453(2)$, $\gamma = 90$, V = 4220.3(9) Å³, Z = 4, $\rho_{calculated} = 2.132$ g cm⁻³, $\mu = 9.056$ mm⁻¹, T = 100(2) K. $\lambda = 0.71073$ Å. Reflections collected/unique = 35597/9770 [*R*(int) = 0.0276], final *R* indices [$I > 2\sigma(I)$], R1 = 0.0309, wR2 = 0.0590.

Crystal data for **2**: C₁₂H₂₈Mo₂O₂P₂Se₆, $M_r = 931.92$, monoclinic, space group P2(1)/c, a = 11.5073(12) Å, b = 14.1178(15) Å, c = 16.0926(17) Å, $\alpha = 90$, $\beta = 97.671(2)$, $\gamma = 90$, V = 2591.0(5) Å³, Z = 4, $\rho_{calculated} = 2.389$ g cm⁻³, $\mu = 9.525$ mm⁻¹, T = 100(2) K. $\lambda = 0.71073$ Å. Reflections collected/unique = 15944/6046 [*R*(int) = 0.0889], final *R* indices [$I > 2\sigma(I)$], R1 = 0.1043, wR2 = 0.1299.

Crystal data for **3**: C₁₈H₄₂InP₃Se₆, $M_r = 940.01$, monoclinic, space group P2(1)/n, a = 15.925(3) Å, b = 10.4450(17) Å, c = 37.635(6) Å, $\alpha = 90$, $\beta = 92.853(3)$, $\gamma = 90$, V = 6252.3(18) Å³, Z = 8, $\rho_{calculated} = 1.997$ g cm⁻³, $\mu = 7.901$ mm⁻¹, T = 100(2) K. $\lambda = 0.71073$ Å. Reflections collected/unique = 52875/14861 [*R*(int) = 0.0789], final *R* indices [$I > 2\sigma(I)$], R1 = 0.0523, wR2 = 0.0602.

Crystal data for 4: $C_{18}H_{42}GaP_3Se_6$, $M_r = 894.91$, monoclinic, space group P2(1)/c, a = 8.7140(12) Å, b = 20.684(3) Å, c = 16.941(2) Å, $\alpha = 90$, $\beta = 99.457(2)$, $\gamma = 90$, V = 3012.0(7) Å³, Z = 4, $\rho_{calculated} = 1.974$ g cm⁻³, $\mu = 8.330$ mm⁻¹, T = 100(2) K. $\lambda = 0.71073$ Å. Reflections collected/unique = 25581/7111 [*R*(int) = 0.0309], final *R* indices [$I > 2\sigma(I)$], *R*1 = 0.0297, w*R*2 = 0.0541.

- R. C. Mehrotra, G. Srivastava and B. P. S. Chauhan, *Coord. Chem. Rev.*, 1984, **55**, 207; B. Walther, *Coord. Chem. Rev.*, 1984, **60**, 67; I. Haiduc, *J. Organomet. Chem.*, 2001, **623**, 29; Y. Takahashi, R. Yuki, M. Sugiura, S. Motojima and K. Sugiyama, *J. Cryst. Growth*, 1980, **50**, 491; C. Byrom, M. A. Malik, P. O'Brien, A. J. P. White and D. J. Williams, *Polyhedron*, 2000, **19**, 211.
- W. Kuchen and H. Hertel, Angew. Chem., Int. Ed. Engl., 1969, 8, 89;
 W. Kuchen and B. Knop, Angew. Chem., Int. Ed. Engl., 1965, 4, 244;
 W. Kuchen, J. Metten and A. Judat, Chem. Ber., 1964, 97, 2306;
 A. Müeller, V. V. K. Rao and P. Christophliemk, J. Inorg. Nucl. Chem., 1974, 36, 472;
 A. Müller, V. V. K. Rao and P. Christophliemk, J. Inorg. Nucl. Chem., 1972, 34, 345;
 A. Müller, V. V. K. Rao and P. Christophliemk, J. Inorg. Nucl. Chem., 1972, 34, 345;
 A. Müller, V. V. K. Rao and P. Christophliemk, J. Inorg. Nucl. Chem., 1971, 104, 1905;
 M. J. Pilkington, A. M. Z. Slawin, D. J. Williams and J. D. Woollins, Polyhedron, 1991, 10, 2641;
 B. Bildstein and F. Sladky, Phosphorus, Sulfur Silicon Relat. Elem., 1990, 47, 341.
- 3 C. Q. Nguyen, A. Adeogun, M. Afzaal, M. A. Malik and P. O'Brien, *Chem. Commun.*, 2005, DOI: 10.1039/b603197h.
- 4 J. G. Winjnhoven, T. E. M. van den Hark and P. T. Beurskens, J. Mol. Struct., 1972, 2, 189.
- 5 D. Fenske, A. Rothenberger and M. S. Fallah, Z. Anorg. Allg. Chem., 2004, 630, 943.
- 6 J. Dirand-Colin, M. Schappacher, L. Ricard and R. Weiss, J. Less-Common Met., 1977, 54, 91.
- 7 R. P. Davies, C. V. Francis, A. P. S. Jurd, M. G. Martinelli, A. J. P. White and D. J. Williams, *Inorg. Chem. Commun.*, 2004, 4802.
- 8 J. Zuckerman-Schpector, I. Haiduc, C. Silvestru and R. Cea-Olivares, *Polyhedron*, 1995, 14, 3087.
- 9 J.-Ho Park, P. O'Brien, A. J. P. White and D. J. Williams, *Inorg. Chem.*, 2001, 40, 3629.
- V. Garcia-Montalvo, R. Cea-Olivares, D. J. Williams and G. Espinosa-Perez, *Inorg. Chem.*, 1996, **35**, 3948; E. G. Zaitseva, I. A. Baidina, P. A. Stabnikov, S. V. Borisov and I. K. Igumenov, *Zh. Strukt. Khim.*, 1990, **31**, 184.
- 11 K. Dymock, G. J. Palenok, J. Slezak, C. L. Raston and A. H. White, J. Chem. Soc., Dalton Trans., 1976, 28; S. Bhattacharya, N. Seth, D. K. Srivastava, V. D. Gupta, H. Noth and M. Thomann-Albach, J. Chem. Soc., Dalton Trans., 1996, 2815.
- 12 G. M. Sheldrick, SHELXL-97, Program for refinement of crystal structures, University of Göttingen, Germany, 1997; G. M. Sheldrick, SHELXS-97, Program for solution of crystal structures, University of Göttingen, Germany, 1997.
- 13 Bruker, SHELXTL. Version 6.10, Bruker AXS Inc., 2000.